## 1.0X0.5mm SMD CHIP LED LAMP

Part Number: KPHHS-1005SECK

Super Bright Orange

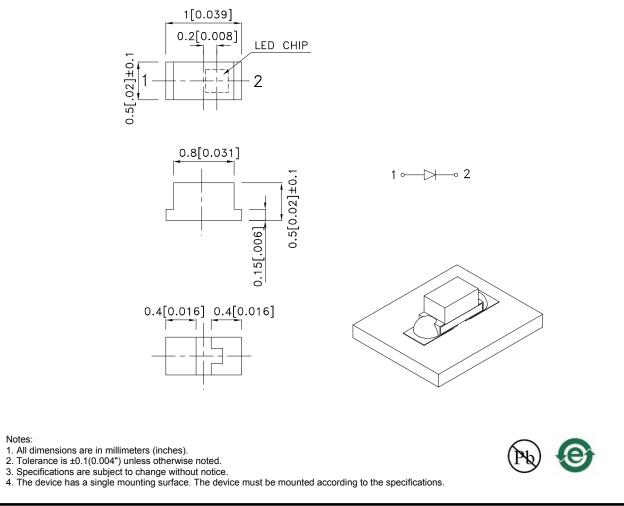
#### Features

- 1.0mmX0.5mm SMT LED, 0.5mm THICKNESS.
- LOW POWER CONSUMPTION.
- WIDE VIEWING ANGLE.
- IDEAL FOR BACKLIGHT AND INDICATOR.
- VARIOUS COLORS AND LENS TYPES AVAILABLE.
- PACKAGE: 2000PCS / REEL .
- MOISTURE SENSITIVITY LEVEL : LEVEL 3.
- RoHS COMPLIANT.

### Description

The Super Bright Orange device is made with InGaAIP (on GaAs substrate) light emitting diode chip.

#### **Package Dimensions**



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## Soloction Guida

Part No.	Dice	Iv (mcd) [2] @ 20mA		/	Viewing Angle [1]	
			Min.	Тур.	201/2	
KPHHS-1005SECK	Super Bright Orange (InGaAIP)	WATER CLEAR	50	160	120°	

Notes:

1.  $\theta$ /2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value. 2. Luminous intensity/ luminous Flux: +/-15%.

## Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Device	Тур.	Max.	Units	Test Conditions
λpeak	Peak Wavelength	Super Bright Orange	610		nm	IF=20mA
λD [1]	Dominant Wavelength	Super Bright Orange	601		nm	IF=20mA
Δλ1/2	Spectral Line Half-width	Super Bright Orange	29		nm	IF=20mA
С	Capacitance	Super Bright Orange	15		pF	VF=0V;f=1MHz
VF [2]	Forward Voltage	Super Bright Orange	2.1	2.5	V	I⊧=20mA
lr	Reverse Current	Super Bright Orange		10	uA	Vr=5V

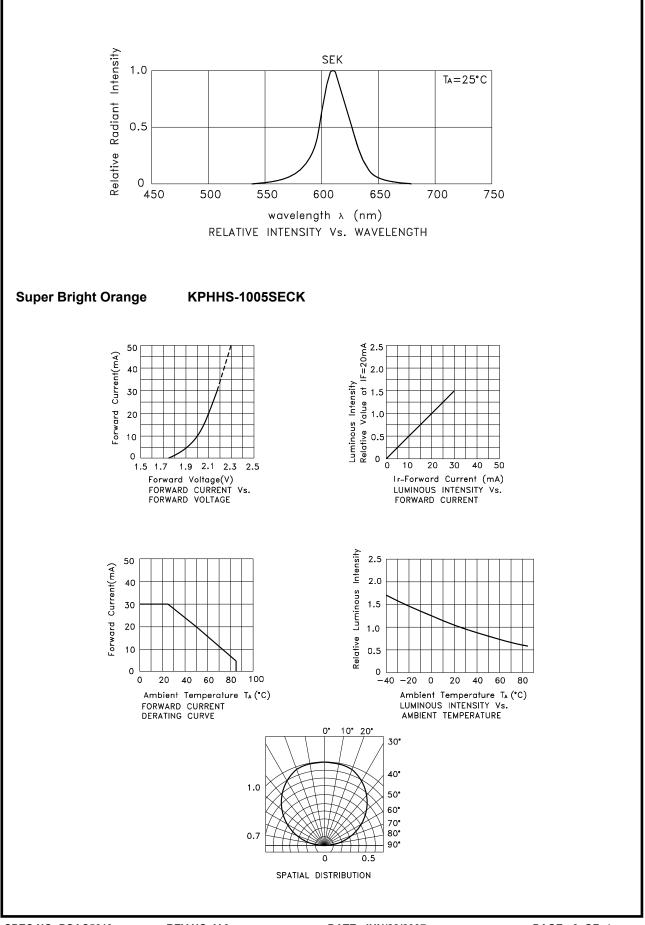
Notes:

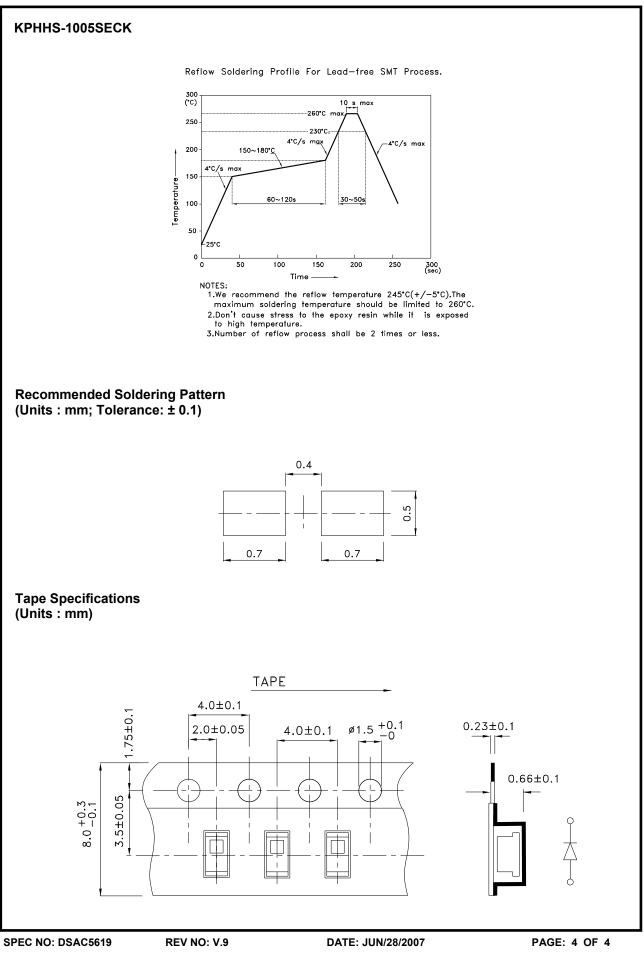
1.Wavelength: +/-1nm. 2. Forward Voltage: +/-0.1V.

## Absolute Maximum Ratings at TA=25°C

Parameter	Super Bright Orange	Units		
Power dissipation	75	mW		
DC Forward Current	30	mA		
Peak Forward Current [1]	195	mA		
Reverse Voltage	5	V		
Operating Temperature	-40°C To +85°C			
Storage Temperature	-40°C To +85°C			

Note: 1. 1/10 Duty Cycle, 0.1ms Pulse Width.





DRAWN: Y.L.LI